

Application Data Sheet

Application Information

Application number:: Unassigned
Filing Date:: 01/07/2004
Application Type:: Regular
Subject Matter:: Utility
Suggested classification::
Suggested Group Art Unit::
CD-ROM or CD-R?:: None
Computer Readable Form (CRF)?:: No
Title:: III-V GROUP NITRIDE SYSTEM
SEMICONDUCTOR SUBSTRATE
Attorney Docket Number:: 035532-0138
Request for Early Publication?:: No
Request for Non-Publication?:: No
Suggested Drawing Figure::
Total Drawing Sheets:: 4
Small Entity?:: No
Petition included?:: No
Secrecy Order in Parent Appl.?:: No

Applicant Information

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Masatomo
Family Name:: SHIBATA
City of Residence:: Tokyo
Country of Residence:: Japan

Street of mailing address:: c/o HITACHI CABLE, LTD.
6-1, Otemachi 1-chome
Chiyoda-ku, Tokyo
Country of mailing address:: Japan

Correspondence Information

Correspondence Customer Number:: 22428
E-Mail address:: PTOMailWashington@Foley.com

Representative Information

Representative Customer Number::	22428	
---	-------	--

Domestic Priority Information

Application::	Continuity Type::	Parent Application::	Parent Filing Date::

Foreign Priority Information

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	2003-368828	10/29/2003	Yes

Assignee Information

Assignee name:: HITACHI CABLE, LTD.